- State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Plastic and Ceramic 300-mil DIPs (J, N)

description

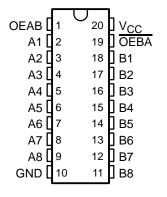
The 'BCT623 bus transceiver is designed for asynchronous communication between data buses. The control function implementation allows for maximum flexibility in timing. The 'BCT623 provides true data at its outputs.

This device allows data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the <u>logic</u> levels at the output-enable (OEAB and OEBA) inputs.

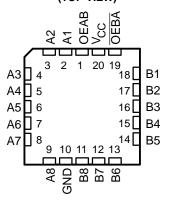
The output-enable inputs can be used to disable the device so that the buses are effectively isolated. The dual-enable configuration gives the transceivers the capability of storing data by simultaneously enabling OEAB and OEBA. Each output reinforces its input in this configuration. When both OEAB and OEBA are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 in all) will remain at their last states.

The SN54BCT623 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT623 is characterized for operation from 0°C to 70°C.

SN54BCT623 . . . J OR W PACKAGE SN74BCT623 . . . DW OR N PACKAGE (TOP VIEW)



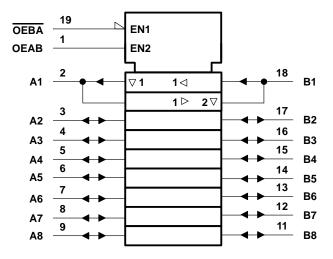
SN54BCT623 . . . FK PACKAGE (TOP VIEW)



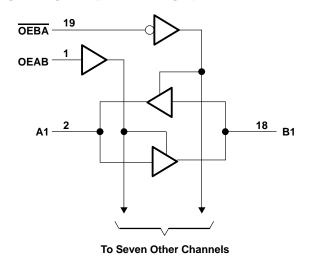
FUNCTION TABLE

INP	UTS	OPERATION					
OEBA	OEAB	OPERATION					
L	L	B data to A bus					
L	Н	B data to A bus, A data to B bus					
Н	L	Isolation					
Н	Н	A data to B bus					

logic symbol†



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		– 0.5 V to 7 V
Input voltage range: Control inputs (see N	Note 1)	– 0.5 V to 7 V
I/O ports (see Note 1	1)	– 0.5 V to 5.5 V
Voltage range applied to any output in the	e disabled or power-off state, VO	– 0.5 V to 5.5 V
Voltage range applied to any output in the	e high state, V _O	– 0.5 V to V _{CC}
Input clamp current, I _{IK}		
Current into any output in the low state: S	SN54BCT623	96 mA
S	SN74BCT623	128 mA
Operating free-air temperature range: S	SN54BCT623	– 55°C to 125°C
S	SN74BCT623	0°C to 70°C
Storage temperature range		– 65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

					SN54BCT623			SN74BCT623		
				NOM	MAX	MIN	NOM	MAX	UNIT	
VCC	Supply voltage		4.5	5	5.5	4.5	5	5.5	V	
VIH	High-level input voltage		2			2			V	
VIL	Low-level input voltage				0.8			0.8	V	
Ι _{ΙΚ}	Input clamp current				-18			-18	mA	
I _{OH} High-level ou	High lovel output outropt	A port			-3			-3	mA	
	riigii-ievei output current	B port			-12			-15	ША	
IOL Low-level out	Low lovel output ourrent	A port			20			24		
	Low-level output current	B port			48			64	mA	
T _A	Operating free-air temperature		-55		125	0		70	°C	



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54BCT623			SN74BCT623			UNIT
'	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	MIN	TYP†	MAX	UNII
VIK		$V_{CC} = 4.5 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V
	A port	V _{CC} = 4.5 V	$I_{OH} = -1 \text{ mA}$	2.5	3.4		2.5	3.4		
		VCC = 4.5 V	$I_{OH} = -3 \text{ mA}$	2.4	3.3		2.4	3.3		
Vон			$I_{OH} = -3 \text{ mA}$	2.4	3.3		2.4	3.3		V
	B port	V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2	3.2					
			$I_{OH} = -15 \text{ mA}$				2	3.1		
	A port	V _{CC} = 4.5 V	$I_{OL} = 20 \text{ mA}$		0.3	0.5				V
VOL	Aport	VCC = 4.5 V	$I_{OL} = 24 \text{ mA}$					0.35	0.5	
VOL	B port	V _{CC} = 4.5 V	$I_{OL} = 48 \text{ mA}$		0.38	0.55				
			$I_{OL} = 64 \text{ mA}$					0.42	0.55	
	A or B port	V _{CC} = 5.5 V,	VI =55.5/ v			1			1	mA
I _I	OEAB or OEBA					0.1			0.1	ША
ı+	A or B port	V _{CC} = 5.5 V,	V _I =27.Y' v			70			70	μΑ
¹IH [‡]	OEAB or OEBA					20			20	μΑ
† A	A or B port	V _{CC} = 5.5 V,	۷ _I =%:۶ ۷			-0.65			-0.65	_{mA}
I _{IL} ‡	OEAB or OEBA	VCC = 0.0 V,	V = 0.0 V			-0.6			-0.6	1117 (
I _{OS} §	A port	V _{CC} = 5.5 V,	V _O = 0	-60		-150	-60		-150	mA
IOS	B port		V() = 0	-100		-225	-100		-225	ША
ICCL	A to B	V _{CC} = 5.5 V			58	92		58	92	mA
ICCH	A to B	V _{CC} = 5.5 V			33	53		33	53	mA
Iccz		V _{CC} = 5.5 V			6	11		6	11	mA
Ci	OEAB or OEBA	V _{CC} = 5 V,	V _I = 2.5 V or 0.5 V		5			5		рF
C.	A to B	V _{CC} = 5 V,	V _O = 2.5 V or 0.5 V		9			9		nE.
C _{io}	B to A	vCC = 5 v,	ν _O = 2.5 ν οι 0.5 ν		12			12		pF

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, C_{L} = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_{A} = 25°C			V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX †				UNIT
			′BCT623			SN54B	CT623	SN74BCT623		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX]
t _{PLH}	А	В	0.5	3.1	4.7	0.5	5.3	0.5	5.2	ns
t _{PHL}		В	1.7	4.9	6.9	1.7	7.6	1.7	7.4	115
t _{PLH}	В	A	0.9	4.1	5.9	0.9	6.8	0.9	6.7	ns
^t PHL		Α	1.8	5.3	7.6	1.8	8.3	1.8	8	115
^t PZH		А	3.1	6.8	9.1	3.1	10.7	3.1	10.6	ns
^t PZL	OEBA	Α	3.3	7.2	9.6	3.3	11.3	3.3	10.7	115
^t PHZ	<u>OEBA</u>	А	1.9	6.1	8.3	1.9	10.6	1.9	9.8	ns
tPLZ		A	1.1	4.6	7	1.1	8.1	1.1	7.8	115
^t PZH	OEAB	В	2	5	6.8	2	7.8	2	7.6	ns
^t PZL		ט	2.7	6.2	8	2.7	9.3	2.7	8.9	115
^t PHZ	OEAB	В	1.1	4.6	6.5	1.1	8	1.1	7.7	ns
t _{PLZ}		U	0.3	3.2	6.3	0.3	7.2	0.3	7.1	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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